



Precision, Wide-Bandwidth Quad SPDT Analog Switch

Features

- \rightarrow Single Supply Operation (+2V to +6V)
- → Rail-to-Rail Analog Signal Dynamic Range
- \rightarrow Low On-Resistance (6 Ω typ with 5V supply) Minimizes Distortion and Error Voltages
- \rightarrow On-Resistance Matching Between Channels, 0.4 Ω Typ.
- \rightarrow On-Resistance Flatness, $<2\Omega$ Typ.
- → Low Charge Injection Reduces Glitch Errors, Q = 6pC Typ.
- → Replaces Mechanical Relays
- → High Speed. t_{ON}, 8ns Typ.
- → Low Crosstalk: -100dB @ 10 MHz
- → Low Off-Isolation: -57dB @ 10 MHz
- → Wide -3dB Bandwidth: 230 MHz
- → High-Current Channel Capability: >100mA
- → TTL/CMOS Logic Compatible
- \rightarrow Low Power Consumption (0.5 μ W typ.)
- → Packaging (Pb-free & Green Available):
 - -16-pin SOIC (W)
 - -16-pin QSOP (Q)

Applications

- → Audio, Video Switching and Routing
- → LAN Switches
- → Telecommunication Systems
- → Battery-Powered Systems

Truth Table

EN	IN	ON Switch
0	0	NC ₁ , NC ₂ , NC ₃ , NC ₄
0	1	NO ₁ , NO ₂ , NO ₃ , NO ₄
1	X	None. Disabled

Description

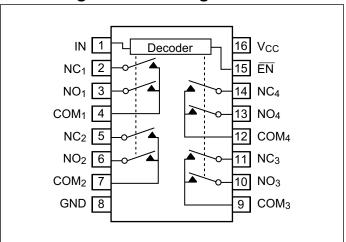
The PI5A100 is an improved Quad Single-pole double-throw (4SPDT) CMOS analog switch designed to operate with a single +2V to +6V power supply. The $\overline{\rm EN}$ pin may be used to place all switches in a high-impedance state. This high precision device is ideal for low-distortion audio, video, and data switching and routing.

Each switch conducts current equally well in either direction when on. In the off state each switch blocks voltages up to the power-supply rails.

The PI5A100 is fully specified with +5V, and +3.3V supplies. With +5V, it guarantees less than 10Ω On-Resistance. On-Resistance matching between channels is within 2Ω . On-Resistance flatness is less than 4Ω over the specified range. The PI5A100 guarantees fast switching speeds (t_{ON} < 12ns).

The PI5A100 is available in the narrow-body SOIC and QSOP packages for operation over the industrial (-40°C to +85°C) temperature range.

Block Diagram/Pin Configuration



Notes:

- 1. Switches shown for logic "0" input.
- 2. NC = Normally Closed; NO = Normally Open





Absolute Maximum Ratings

Voltages Referenced to Gnd	
V _{CC}	
V _{IN} , V _{COM} , V _{NC} , V _{NO} (1)	
OI	30mA, whichever occurs first
Current (any terminal except CO	M, NO, NC)30mA
Current, COM, NO, NC	
(pulsed at 1ms, 10% duty cycle).	120mA

Thermal Information

Continuous Power Dissipation
Narrow SOIC & QSOP (derate 8.7mW/°C above +70°C)
(derate 8.7mW/°C above +70°C)
Storage Temperature $$ -65°C to +150°C
Lead Temperature (soldering, 10s) +300°C

Notes:

- 1. Signals on NC, NO, COM, or IN exceeding V_{CC} or GND are clamped by internal diodes. Limit forward diode current to 30mA.
- 2. Caution: Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions beyond those indicated in the operational sections of this specification is not implied.

Electrical Specifications - Single +5V Supply ($V_{CC} = +5V \pm 10\%$, GND = 0V, $V_{INH} = 2.4V$, $V_{INL} = 0.8V$)

Symbol	Parameter	TestConditions	Temp.	Min. ⁽¹⁾	Typ. ⁽²⁾	Max. ⁽¹⁾	Units	
Analog Switch								
V _{ANALOG}	Analog Switch Range ⁽¹⁾		Full	0		V _{CC}	V	
Day	O. D. 14		25		8	10		
R _{ON}	On-Resistance	$V_{CC} = 4.5 \text{V}, I_{COM} = -30 \text{mA},$	Full			12		
AD our	On-Resistance Match	V_{NO} or $V_{NC} = +2.5V$	25		0.8	2		
$\Delta R_{ m ON}$	Between Channels ⁽⁶⁾		Full			4	Ω	
R _{FLAT(ON)}	On-Resistance Flatness ⁽⁵⁾	$V_{CC} = 5V, I_{COM} = -30mA,$	25		2	3		
	On-Resistance Flatness	V_{NO} or $V_{NC} = +2.5V$	Full			4		
I _{NO(OFF)} or I _{NC(OFF)}	JO or NC OEE Looks (6)	$V_{CC} = 5.5C, I_{COM} = 0V,$	25		0.07			
	INO of NC OFF Leakage	V_{NO} or $V_{NC} = 4.5V$	Full -80		80			
I _{COM(OFF)}	(6)	$V_{CC} = 5.5V, I_{COM} = 4.5V,$ V_{NO} or $V_{NC} = \pm 4.5V$	25		0.01			
			Full	-80		80	nA	
I _{COM(ON)}	COM ON Leakage	$V_{CC} = 5.5V$, $I_{COM} = 4.5V$,	25		0.016			
	Current ⁽⁶⁾	V_{NO} or $V_{NC} = \pm 4.5V$	Full	-80		80		





Electrical Specifications - Single +5V Supply ($V_{CC} = +5V \pm 10\%$, GND = 0V, $V_{INH} = 2.4V$, $V_{INL} = 0.8V$) CONTINUED

Symbol	Parameter	TestConditions	Temp.	Min.(1)	Typ.(2)	Max. ⁽¹⁾	Units	
Logic Input	<u>. </u>			•	•	•		
V_{IH}	Input High Voltage	Guaranteed logic High Level	Full	2			V	
$V_{\rm IL}$	Input Low Voltage	Guaranteed logic Low Level				0.8	ĺ	
I _{INH}	Input Current with Input Voltage High	$V_{IN} = 2.4V$, all others = $0.8V$	Full	-1	0.005	1	- μΑ	
I _{INL}	Input Current with Input Voltage Low	$V_{IN} = 0.8V$, all others = 2.4V		-1	0.005	1		
Dynamic								
4	Turn-On Time		25		8	15		
t_{ON}	Turn-On Time	V - 5V Cas Figure 1	Full			20]	
4	Turn-Off Time	$V_{CC} = 5V$, See Figure 1	25		3.5	7	ns -	
t _{OFF}	Turn-OII Time		Full			10		
Q	Charge Injection ⁽³⁾	$C_L = 1$ nF, $V_{GEN} = 0$ V, $R_{GEN} = 0\Omega$, See Figure 2	25			10	рC	
O _{IRR}	Off Isolations	$R_L = 50\Omega$, $C_L = 5pF$, f = 10MHz, See Figure 3			-57		1D	
X _{TALK}	Crosstalk ⁽⁸⁾	$R_L = 50\Omega$, $C_L = 5pF$, f = 10MHz, See Figure 4			-100		dB	
C _(OFF)	NC or NO Capacitance	f=1kHz, See Figure 5			8			
C _{COM(OFF)}	COM OFF Capacitance				14		pF	
C _{COM(ON)}	COM ON Capacitance	f = 1kHz, See Figure 6			18			
BW	-3db Bandwidth	$R_L = 50\Omega$ See Figure 7	Full		230		MHz	
D	Distortion	$R_L = 10k\Omega$			0.2		%	
Supply								
V_{CC}	Power-Supply		Full	2		6	V	
I _{CC}	Postitive Supply Current	$V_{CC} = 5.5V$, $V_{IN} = 0V$ or V_{CC} , all channels on or off				1	μА	

Notes:

- 1. The algebraic convention, where the most negative value is a minimum and the most positive is a maximum, is used in this data sheet.
- 2. Typical values are for DESIGN AID ONLY, not guaranteed or subject to production testing.
- 3. Guaranteed by design
- 4. $\Delta R_{ON} = R_{ON} \max R_{ON} \min$
- 5. Flatness is defined as the difference between the maximum and minimum value of On-Resistance measured.
- 6. Leakage parameters are 100% tested at maximum rated hot temperature and guaranteed by correlation at +25°C.
- 7. Off Isolation = $20\log_{10} [V_{COM} / (V_{NO} \text{ or } V_{NC})]$. See figure 3.
- 8. Between any two switches. See figure 4.-





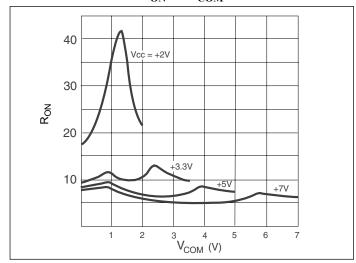
Electrical Specifications - Single +3.3V Supply ($V_{CC} = +5V \pm 10\%$, GND = 0V, $V_{INH} = 2.4V$, $V_{INL} = 0.8V$)

Symbol	Parameter	TestConditions	Temp.	Min. ⁽¹⁾	Typ.(2)	Max. ⁽¹⁾	Units
Analog Switch	Analog Switch						
	Analog Switch Range ⁽¹⁾			0		V _{CC}	V
Dov	On-Resistance		25		12	18	Ω
R _{ON}	On-Resistance	$V_{CC} = 4.5 \text{V}, I_{COM} = -30 \text{mA},$	Full				
AD	On-Resistance Match	V_{NO} or $V_{NC} = +2.5V$	25		5		
$\Delta R_{ m ON}$	Between Channels ⁽⁶⁾		Full				
R _{FLAT(ON)}	On-Resistance Flatness ⁽⁵⁾	$V_{CC} = 5V, I_{COM} = -30mA,$	$_{CC} = 5V, I_{COM} = -30mA,$ 25	2	4		
	On-Resistance Flatness	V_{NO} or $V_{NC} = +2.5V$	Full			5	
Dynamic	Dynamic						
t _{ON} Turn-On	Turn On Time		25	14 2	25		
	Turn-On Time	V = = 5V Coo Figure 1	Full		40	40] "
t _{OFF}	Turn Off Times	$V_{CC} = 5V$, See Figure 1	25		4.5	12	ns
	Turn-Off Time		Full			20	
Q	Charge Injection ⁽³⁾	$C_L = 1$ nF, $V_{GEN} = 0$ V, $R_{GEN} = 0$ Ω, See Figure 2	25		5	10	pC
Supply							
I _{CC}	Postitive Supply Current	$V_{CC} = 3.6V$, $V_{IN} = 0V$ or V_{CC} , all channels on or off	Full			1	μА

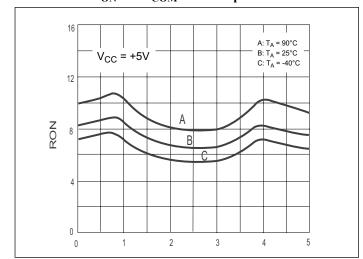


Typical Operating Characteristics (T_A =+25°C, unless otherwise noted)

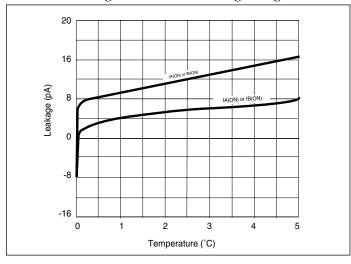
Ron vs. V_{COM}



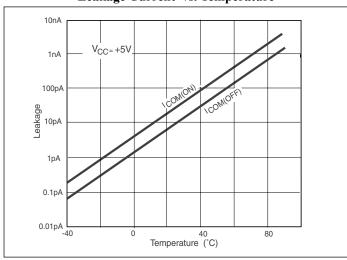
RON vs. VCOM and Temperature



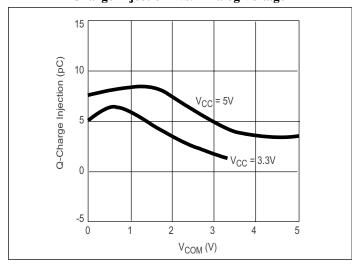
Leakage Currents vs. Analog Voltage



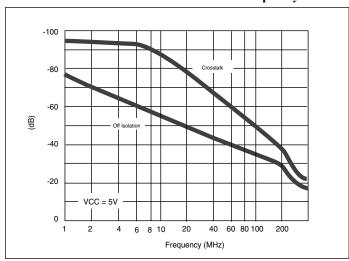
Leakage Current vs. Temperature



Charge Injection vs. Analog Voltage



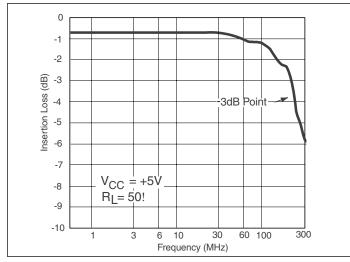
Crosstalk and Off-Isolation vs. Frequency



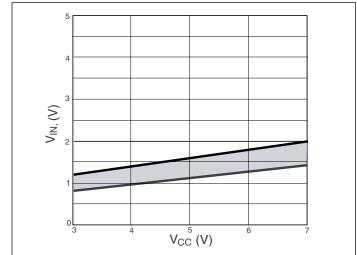




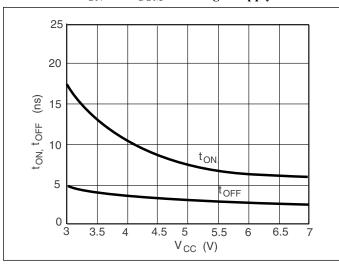
Insertion Loss vs. Frequency



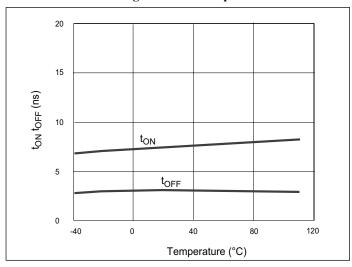
Input Switching Threshold vs. Supply Voltage



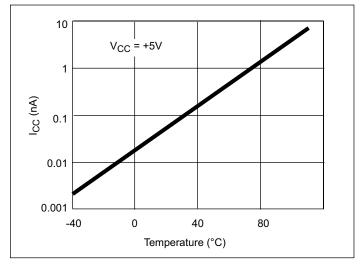
RON vs. VCOM and Single Supply



Switching Times vs. Temperature



Supply Current vs. Temperature







Test Circuits/Timing Diagrams

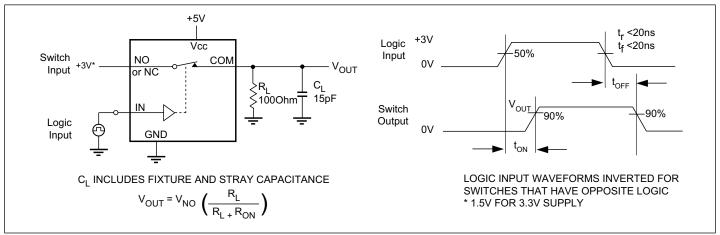


Figure 1. Switching Time

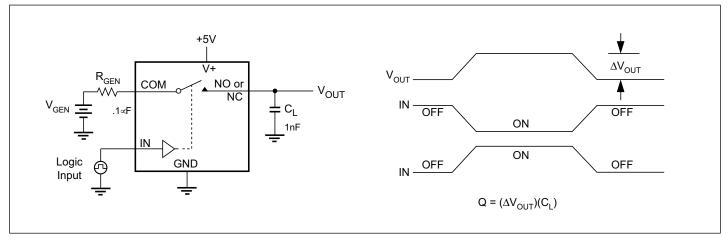
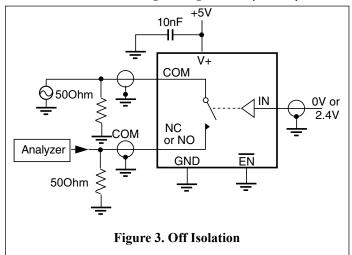


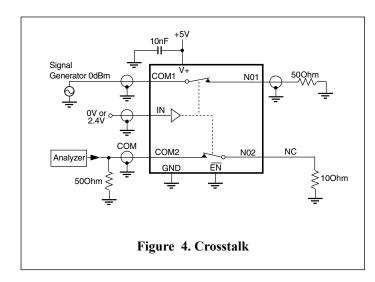
Figure 2. Charge Injection

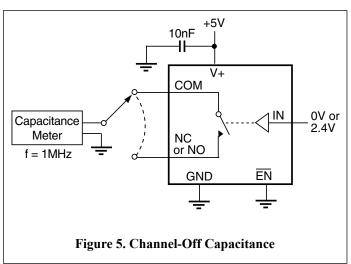


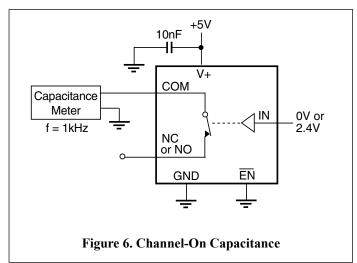


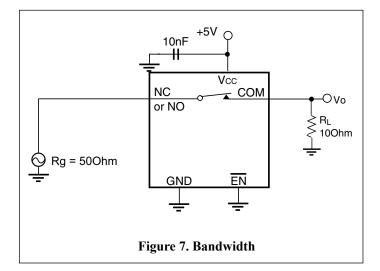
Test Circuits/Timing Diagrams (cont.)















Applications Information

Overvoltage Protection

Proper power-supply sequencing is recommended for all CMOS devices. Do not exceed the absolute maximum ratings, because stresses beyond the listed ratings may cause permanent damage to the devices. Always sequence V+ on first, followed by V-, and then logic inputs. If power-supply sequencing is not possible, add two small signal diodes or two current limiting resistors in series with the supply pins for overvoltage protection (Figure 8). Adding diodes reduces the analog signal range, but low switch resistance and low leakage characteristics are unaffected.

RGB Switch

Figure 9 illustrates a simple low cost RGB switch. The RGB -to-Composite Decoder produces either NTSC or S-VHS video from an RGB source. Asingle PI5A100 selects one of the two video sources to produce either SVHS, Composite or RGB video outputs. The low insertion loss of the PI5A100 eliminates the need for expensive input/output buffers.

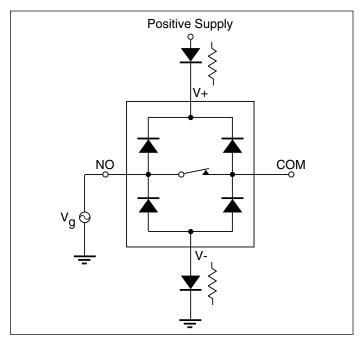


Figure 8: Overvoltage protection is accomplished using two external blocking diodes or two current limiting resistors.

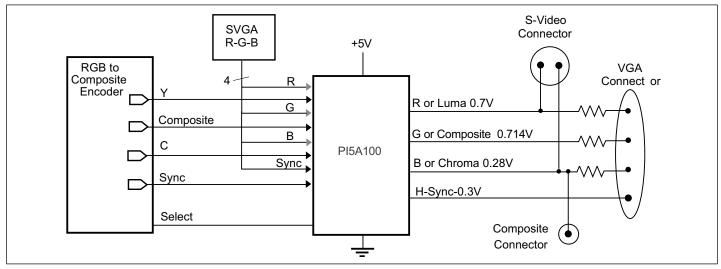


Figure 9: The single PI5A100 is used to select SVHS, VGA or Composite video outputs.





Applications

Audio Muting Function

Figure 8 shows the PI5A100 in an audio card muting application. The original problem was one of excessive popping/clicking noise appearing when connecting disconnecting external loads, and at power on/off. The PI5A100 performs a muting function by grounding the outputs at power on/off and during the transition time. The 32Ω headset impedance demands a very low and very flat switch-on resistance to reduce THD and signal loss.

Paralleling two sections of the PI5A100 produces a Ron of 2.5Ω with an unsurpassed $\pm 0.5\Omega$ flatness.

To handle AC signals it was necessary to power the device with ± 3 V provided by two Zener diodes: Z1 and Z2. The select and Enable control signals are shifted by using two 2.5V Zener diodes Z3,Z4 and pull down resistors connected to -3V.

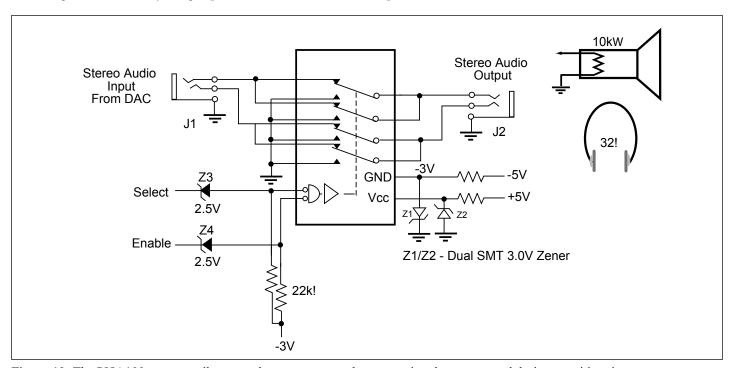


Figure 10: The PI5A100 momentarily mutes the stereo outputs by connecting them to ground during transition times.

Part Marking

W Package



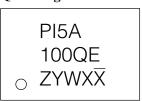
*: Die Rev YY: Year

WW: Workweek

1st X: Assembly Site Code 2nd X: Fab Site Code

Bar above fab code means Cu wire

Q Package



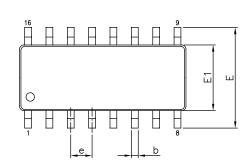
Z: Die Rev

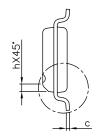
YW: Year & Workweek 1st X: Assembly Code 2nd X: Fab Code



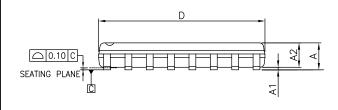


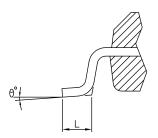
Packaging Mechanical: 16-SOIC (W)





SYMBOLS	MIN.	NOM.	MAX.	
Α	-	_	1.75	
A1	0.10	_	0.25	
A2	1.00	_	_	
b	0.31	_	0.51	
С	0.10	_	0.25	
D	9.80	9.90	10.0	
E	5.80	6.00	6.20	
E1	3.80	3.90	4.00	
е	1.27 BSC			
L	0.40	_	1.27	
h	0.15	_	0.50	
θ°	0	_	8	





NOTES:

1. ALL DIMENSIONS IN MILLIMETERS. ANGLES IN DEGREES.

2. JEDEC OUTLINE: MS-012 AC

3. DIMENSIONS DOES NOT INCLUDE MOLD FLASH,
PROTRUSIONS OR GATE BURRS.

4. THE MIN. DIMENSION OF A2 AND h ARE OUT OF JEDEC SPEC.

PERICOM OF DIODES INCORPORATED

DESCRIPTION: 16-Pin, 150mil Wide SOIC PACKAGE CODE: W

DOCUMENT CONTROL #: PD-1004

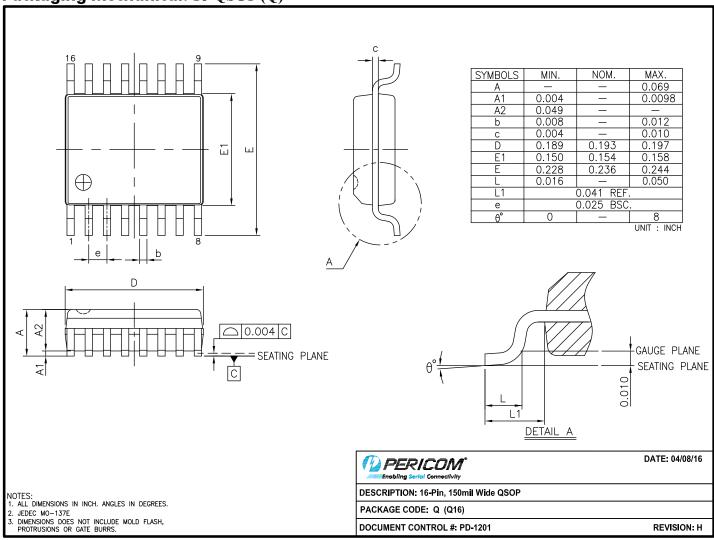
REVISION: G

DATE: 06/30/16





Packaging Mechanical: 16-QSOP(Q)



For latest package info.

 $please\ check: http://www.diodes.com/design/support/packaging/pericom-packaging/packaging-mechanicals-and-thermal-characteristics/pericom-packaging/packaging-mechanicals-and-thermal-characteristics/pericom-packaging-mechanicals-and-thermal-characteristics/pericom-packaging-mechanicals-and-thermal-characteristics/pericom-packaging-packaging-mechanicals-and-thermal-characteristics/pericom-packaging-packaging-mechanicals-and-thermal-characteristics/pericom-packaging-packaging-mechanicals-and-thermal-characteristics/pericom-packaging-packagin$

Ordering Information

Ordering Code	Package Code	Package Description
PI5A100WEX	W	16-pin, 150mil Wide (SOIC)
PI5A100QEX	Q	16-pin, 150mil Wide (QSOP)

Notes:

- Thermal characteristics can be found on the company web site at www.diodes.com/design/support/packaging/
- E = Pb-free and Green
- X suffix = Tape/Reel





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